

Experiment: "Electrical conductivity in two dimensions" Marking Scheme



Part			Maximum points		Total points	
A: Four-point-probe (4PP) measurements						
A 1	Value	1.9 < s < 2.1	0.1	0.6	6	
	Table and Graph	I and V are measured at 4 or more points	0.3			
		Points are properly marked using the majority part of the graph	0.2			
		If I > V	-0.1			
		Missing or incorrect units (either or both)	-0.1			
		Missing axis labels (either or both)	-0.1			
A2	Calculation	1000 Ohm < R < 1200 Ohm with units	0.2	0.2		
А3	Calculation	Either: extremal lines with slopes, error= difference of slopes, or numerical regression analysis. If the dispersion of measurements from the mean line not visible, error propagation from instrument error is allowed or a conclusion that error is negligible.	0.4	0.4		
		Missing or incorrect units (either or both)	-0.1			
		B: Sheet resistivity			0.3	
B1	Calculation	ρ _□ calculation is consistent with A2	0.3	0.3		
		Missing or incorrect units (either or both)	-0.1			
	C: Measurements for different sample dimensions					
C1	Measureme	4 values w/s, ≥ 4 data points per w/s	3	3	3.2	
	nts	3 values 4 w/s	2			
		2 or less values 4 w/s	0			
		4 or 3 values w/s, ≥ 3 data points per w/s	-0.5			
		4 or 3 values w/s, ≥ 2 data points per w/s	-1			
		4 or 3 values w/s, ≥ 1 data points per w/s	-1.5			

Part			Maximum points		Total points
		Missing or incorrect units (either or both)	-0.1		
C2	Calculation	$f(w/s)$ for ≥ 3 values	0.2	0.2	
		f(w/s) for 1 or 2 values	0.1		
		D: Geometrical correction factor			1.9
D1	Graph	Choice of appropriate graph and axis values, so that the marks should lie on a line.	0.8	1	
		Points are properly marked using the major part of the graph; irrespective of graph used	0.2		
		Missing or incorrect labels (either or both)	-0.1		
		Missing or incorrect units (either or both)	-0.1		
D2		Reasonable fit over all marks	0.3	0.9	
		2.2 < a < 3.6	0.3		
		1.8 < a < 2.2, 3.6 < a < 4	0.2		
		-2 < b < -1	0.3		
		Missing or incorrect labels (either or both)	-0.1		
		Missing or incorrect units (either or both)	-0.1		
E: The silicon wafer and van der Pauw-method 3.4					
E1	Table		0.4	0.4	0.1
E 1	rable	0.1 per I and V measurement; max 0.4 points	0.4	0.4	
		Missing or incorrect units (either or both)	-0.1		
E2	Graph and	Points are properly marked using the majority part of the graph	0.1	0.4	
	Calculation	Reasonable fit over all marks	0.1		
		R_{4PP} according to the wafer table ± 15 %, if wafer number is not known use R_{4PP} = 55 Ω	0.2		

Part			Maximum points		Total points
		R_{4PP} according to the wafer table 15.1 30 %, if wafer number is not known use R_{4PP} = 55 Ω	0.1		
		Missing or incorrect labels (either or both)	-0.1		
		Missing or incorrect units (either or both)	-0.1		
E3	Calculation	Consistent calculation of f(w/s) with D2	0.2	0.2	
E 4	Calculation	<i>ρ</i> _□ (4PP)	0.1	0.1	
		No or incorrect units	-0.1		
E 5	Sketch and	Sketch present and makes sense	0.2	0.6	
	table	6 different I and V values are taken	0.4		
		5 different I and V values are taken	0.3		
		4 different I and V values are taken	0.2		
		3 different I and V values are taken	0.1		
		2 or less different I and V values are taken	0		
		V points are extremely unequally spaced	-0.1		
		Missing or incorrect units (either or both)	-0.1		
E 6	Sketch and Sketch should be perpendicular to F5, otherwise table the whole part gets 0 points		rwise	0.6	
	Sketch present, makes sense and perpendicular to the sketch of F5	0.2			
	6 different I and V values are taken	0.4			
		5 different I and V values are taken	0.3		
		4 different I and V values are taken	0.2		
		3 different I and V values are taken	0.1		
		2 or less different I and V values are taken	0		
		V points are extremely unequally spaced	-0.1		
		Missing or incorrect units (either or both)	-0.1		

Part			Maximum points		Total points
E 7	Graph	Points are properly marked using the majority part of the graph	0.1	0.5	
		Reasonable fit over all marks	0.1		
		$\langle R \rangle$ = vdPauw resistance of wafer table ± 10 %, if wafer number is not known use $\langle R \rangle$ = 42 Ω	0.3		
		$\langle R \rangle$ = vdPauw resistance of wafer table ± 10.1 to 20 %, if wafer number is not known use $\langle R \rangle$ = 42 Ω	0.2		
		$\langle R \rangle$ = vdPauw resistance of wafer table ± 20.1 to 30 %, if wafer number is not known use $\langle R \rangle$ = 42 Ω	0.1		
		Missing or incorrect labels (either or both)	-0.1		
		Missing or incorrect units (either or both)	-0.1		
E8	Solve Eqn.	$ ho_{\Box} = \frac{\pi}{\ln 2} \langle R \rangle$ formula is present	0.3	0.4	
	Calculation	Consistent calculation $ ho_\square$	0.1		
		Missing or incorrect units	-0.1		
E 9	Calculation	Value is written with correct units (fraction, decimal and % are accepted)	0.1	0.1	
E10	Calculation	Consistent calculation $ ho$	0.1	0.1	
		Missing or incorrect units	-0.1		

Total number of points	10	
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